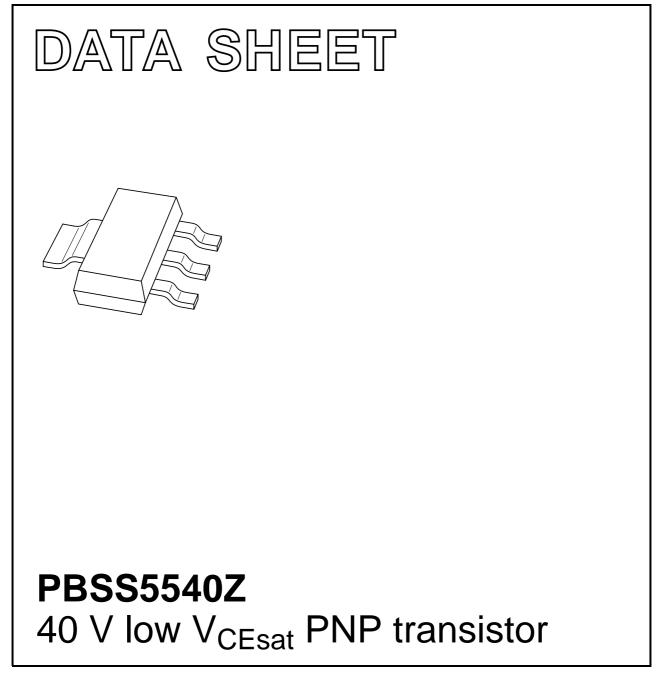
DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 2001 Jan 26 2001 Sep 21



FEATURES

- Low collector-emitter saturation voltage
- High current capability
- Improved device reliability due to reduced heat generation.

APPLICATIONS

- Supply line switching circuits
- Battery management applications
- DC/DC converter applications
- Strobe flash units
- Heavy duty battery powered equipment (motor and lamp drivers)
- MOSFET driver applications.

DESCRIPTION

PNP low V_{CEsat} transistor in a SOT223 plastic package. NPN complement: PBSS4540Z.

MARKING

TYPE NUMBER	MARKING CODE
PBSS5540Z	PB5540

QUICK REFERENCE DATA

SYMBOL	PARAMETER	МАХ	UNIT	
V _{CEO}	emitter-collector voltage	-40	V	
I _C	collector current (DC)	-5	А	
I _{CM}	peak collector current -10		А	
R _{CEsat}	equivalent on-resistance	<80 mΩ		

PINNING

PIN	DESCRIPTION	
1	base	
2	collector	
3	emitter	
4	collector	

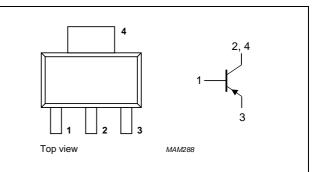


Fig.1 Simplified outline (SOT223) and symbol.

PBSS5540Z

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	-40	V
V _{CEO}	collector-emitter voltage	open base	_	-40	V
V _{EBO}	emitter-base voltage	open collector	_	-6	V
I _C	collector current (DC)		_	-5	А
I _{CM}	peak collector current		_	-10	A
I _{BM}	peak base current		_	-2	А
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$; note 1	_	1.35	W
		$T_{amb} \le 25 \ ^{\circ}C$; note 2	_	2	W
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Notes

- 1. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm².
- 2. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 6 cm². For other mounting conditions, see *"Thermal considerations for SOT223 in the General Part of associated Handbook"*.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	in free air; note 1	92	K/W

Note

1. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm².

PBSS5540Z

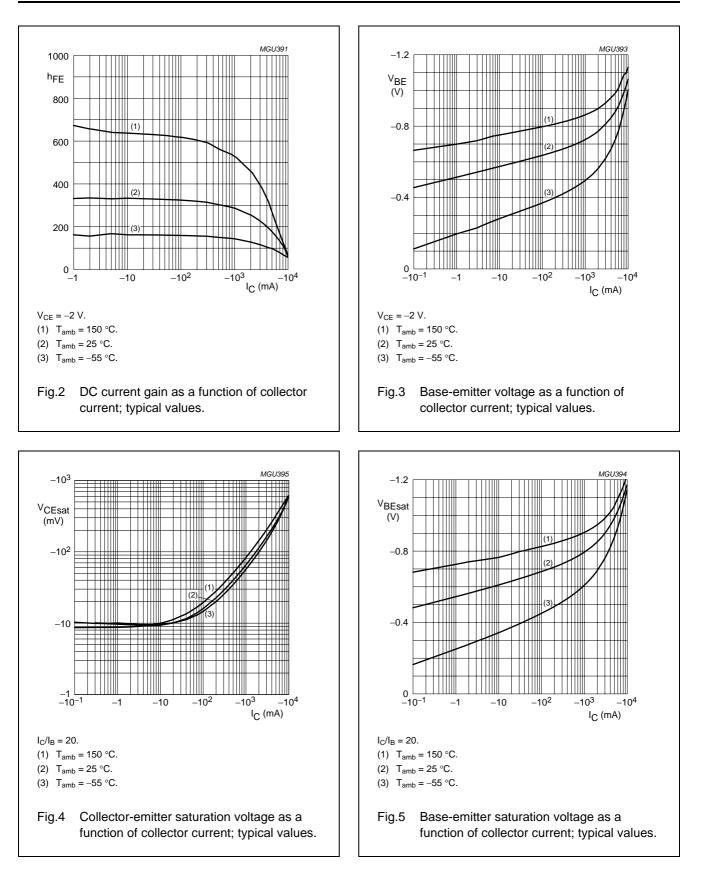
CHARACTERISTICS

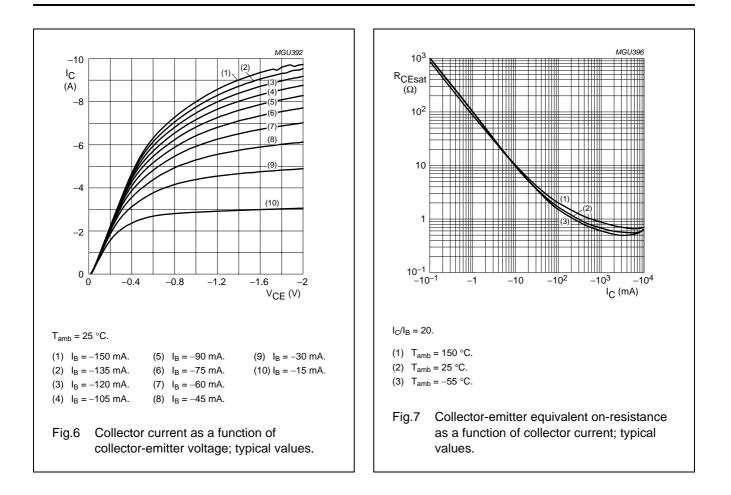
 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = -30 \text{ V}; I_E = 0$	_	_	-100	nA
		$V_{CB} = -30 \text{ V}; I_E = 0; T_j = 150 \text{ °C}$	_	_	-50	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 V; I_C = 0$	-	-	-100	nA
h _{FE}	DC current gain	$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -500 \text{ mA}$	250	350	-	
		$V_{CE} = -2 \text{ V}; I_{C} = -1 \text{ A}; \text{ note } 1$	200	300	-	
		$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -2 \text{ A}; \text{ note } 1$	150	250	-	
		$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -5 \text{ A}; \text{ note } 1$	50	150	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{C} = -500 \text{ mA}; I_{B} = -5 \text{ mA}$	_	-80	-120	mV
		$I_{\rm C} = -1$ A; $I_{\rm B} = -10$ mA	-	-120	-170	mV
		$I_{\rm C} = -2$ A; $I_{\rm B} = -200$ mA	-	-110	-160	mV
R _{CEsat}	equivalent on-resistance	$I_{C} = -2 \text{ A}; I_{B} = -200 \text{ mA}; \text{ note } 1$	-	<55	<80	mΩ
V _{CEsat}	collector-emitter saturation voltage	$I_{C} = -5 \text{ A}; I_{B} = -500 \text{ mA}$	-	-250	-375	mV
V _{BEsat}	base-emitter saturation voltage	$I_{C} = -5 \text{ A}; I_{B} = -500 \text{ mA}$	-	-	-1.3	V
V _{BEon}	base-emitter turn-on voltage	$V_{CE} = -2 V; I_C = -2 A$	_	-0.8	-1.25	V
f _T	transition frequency	$I_{C} = -100 \text{ mA}; V_{CE} = -10 \text{ V};$ f = 100 MHz	60	120	-	MHz
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; \text{ I}_{E} = \text{ I}_{e} = 0;$ f = 1 MHz	-	90	105	pF

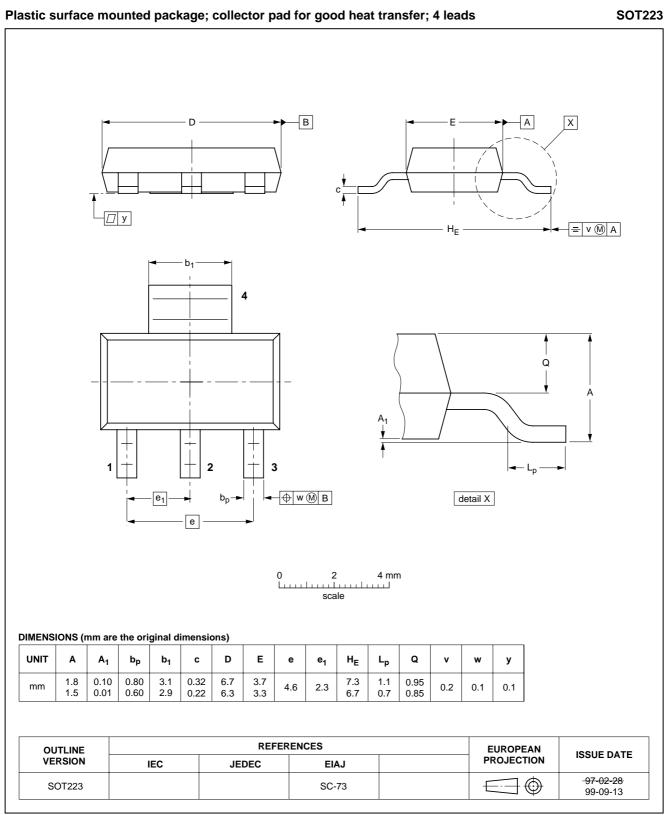
Note

1. Pulse test: $t_p \leq 300~\mu s;~\delta \leq 0.02.$





PACKAGE OUTLINE



PBSS5540Z

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors. No changes were made to the content, except for the legal definitions and disclaimers.

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